

Regular InGaAs Photodiodes IG17-Series

Description

The IG17-series is a panchromatic PIN photodiode with a nominal wavelength cut-off at 1.7 μm . This series has been designed for demanding spectroscopic and radiometric applications. It offers excellent shunt resistance in combination with superior responsivity over a wide range.

Features

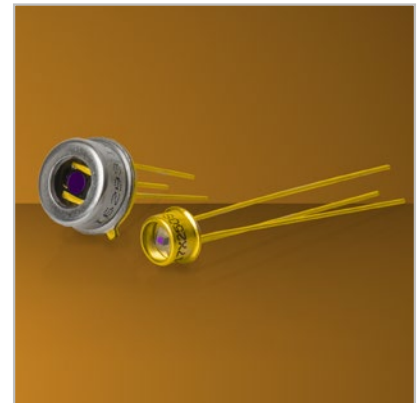
- 50 % cut-off wavelength $\geq 1.65 \mu\text{m}$
- Typical peak responsivity: 1.05 A/W
- Excellent temperature stability
- Reduced edge effect

Applications

- Spectrophotometer
- Diode laser monitoring
- Non-contact temperature measurement
- Flame control
- Moisture monitoring

Versions

- Uncooled
TO-can, SMD, chip only, ceramic substrate, digital module
- Cooled
TE1, TE2, TE3



Optical Characteristics, Specifications @ 25°C ^c

Part Number	Diameter [μm]	50% Cut off Wavelength ^a [μm]	Peak Wave-length ^a [μm]	Peak Responsivity ^{a,b} [A/W]		Responsivity @ 520 nm ^{a,b,d} [A/W]		Responsivity @ 1300 nm ^{a,b} [A/W]		Responsivity @ 1500 nm ^{a,b} [A/W]	
				Min.	Typ.	Min.	Typ.	Min.	Typ.	Min.	Typ.
IG17X250S4i	250	≥1.65 ± 0.1	1.55	0.9	1.05	TBD	0.1	0.77	0.91	0.8	1.0
IG17X500S4i	500										
IG17X1000S4i	1000										
IG17X1300S4i	1300										
IG17X2000G1i	2000										
IG17X3000G1i	3000										

^a Parameter tested on batch level at T = 25°C.

^b Responsivity measured at 0 V Bias.

^c Data are prior to window integration

^d Preliminary data

Electro-Optical Characteristics, Specifications @ 25°C

Part Number	Diameter [μm]	Shunt Impedance @ V _R = 10 mV ^b [MΩ]		Dark Current @ V _R = 5 V ^b [nA]		Peak D* ^a f = 1 kHz [cm Hz ^{1/2} /W]		Peak NEP ^a f = 1 kHz [W/Hz ^{1/2}]	
		Min.	Typ.	Typ.	Max.	Min.	Typ.	Max.	Typ.
IG17X250S4i	250	200	830	0.1	1	5.0 E+12	1.0 E+13	1.0 E-14	5.0 E-15
IG17X500S4i	500	60	200	0.3	2	3.8 E+12	7.0 E+12	1.8 E-14	1.0 E-14
IG17X1000S4i	1000	20	100	1	8	3.1 E+12	7.0 E+12	3.2 E-14	1.4 E-14
IG17X1300S4i	1300	10	45	2	20	2.5 E+12	5.3 E+12	4.5 E-14	2.1 E-14
IG17X2000G1i	2000	6	20	3	30	2.4 E+12	4.4 E+12	5.8 E-14	3.2 E-14
IG17X3000G1i	3000	4	12	10	75	2.4 E+12	4.2 E+12	7.1 E-14	4.1 E-14

^a Parameter tested on batch level

^b Parameter 100% tested

Electrical Characteristics, Specifications @ 25°C

Part Number	Diameter [μm]	Capacitance @ $V_r = 0 V^a$	Forward Voltage
		[pF]	[V]
		Typ.	Typ.
IG17X250S4i	250	15	0.73
IG17X500S4i	500	60	
IG17X1000S4i	1000	215	
IG17X1300S4i	1300	305	
IG17X2000G1i	2000	700	
IG17X3000G1i	3000	1550	

Thermoelectrically Cooled InGaAs Detectors

Part Number	Diameter [μm]	Operating Temperature [°C]	Shunt Impedance @ $V_r = 10 mV^b$		Peak $D^* \text{ } ^\circ$	Peak NEP ^a	Capacitance @
			[MΩ]	[MΩ]	[cm Hz ^{1/2} /W]	[W/Hz ^{1/2}]	$V_r = 0 V^a$
			Min.	Typ.	Typ.	Typ.	Typ.
IG17X1000T7	1000	-20	750	2750	4.1E+13	2.1E-15	215
IG17X1300T7	1300		360	1500	4.0E+13	2.9E-15	305
IG17X2000T7	2000		180	530	3.6E+13	4.9E-15	700
IG17X3000T7	3000		65	295	4.1E+13	6.6E-15	1550
IG17X1000T9	1000	-40	5000	19000	1.1E+14	7.9E-16	215
IG17X1300T9	1300		2000	10000	1.1E+13	1.1E-15	305
IG17X2000T9	2000		1100	4000	1.0E+13	1.7E-15	700
IG17X3000T9	3000		200	400	4.9E+13	5.5E-15	1550

^a Parameter tested on batch level

^b Parameter 100% tested

Absolute Maximum Ratings

	Min.	Max.
Storage Temperature [°C]	-55	+125
Operating Temperature [°C]	-40	+85
Reverse Bias, cw [V]	-	10
Forward Current, cw [mA]	-	1
Soldering Temperature, 5 sec. [°C]	-	260
ESD Damage Threshold, Human Body Model Class 1A*, [V]	250	<500
TE Cooler Voltage [V]	-	3.7
TE Cooler Current [A]	-	1.1

*ANSI/ ESD STN5. 1-2007

Fig. 1: Spectral Response

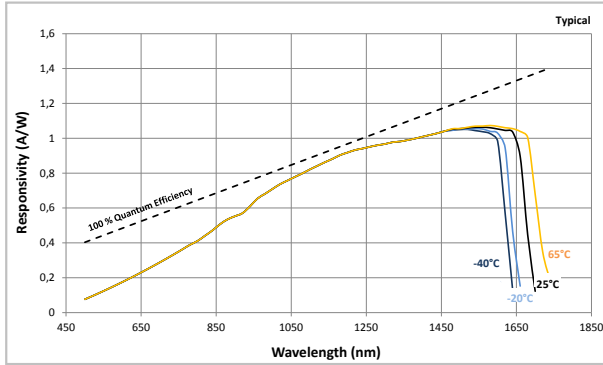


Fig. 2: Dark Current vs. Reverse Voltage

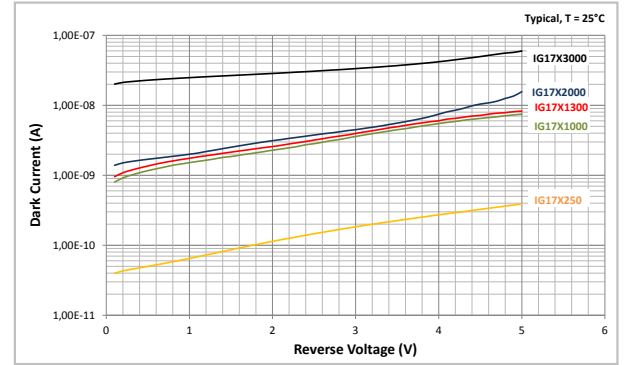


Fig. 3: Shunt vs. Temperature

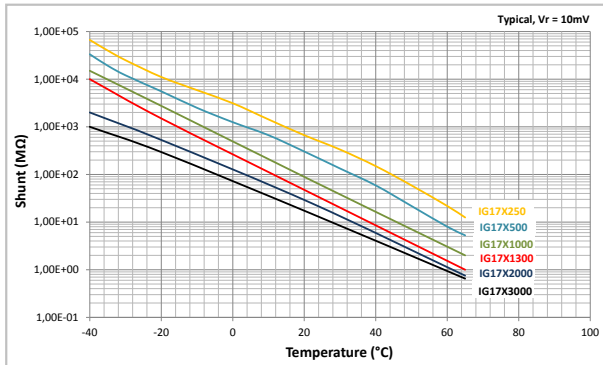


Fig. 4: Detectivity vs. Shunt x Area

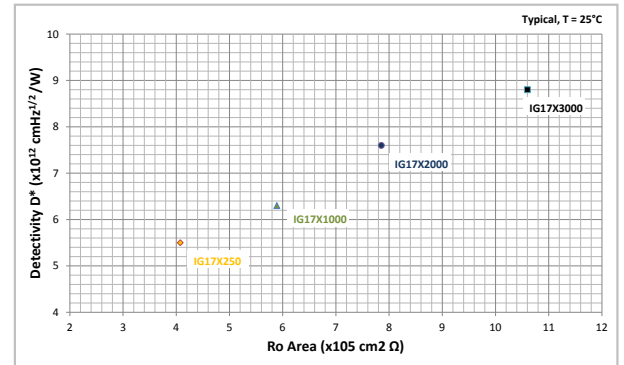


Fig. 5: Capacitance vs. Reverse Voltage

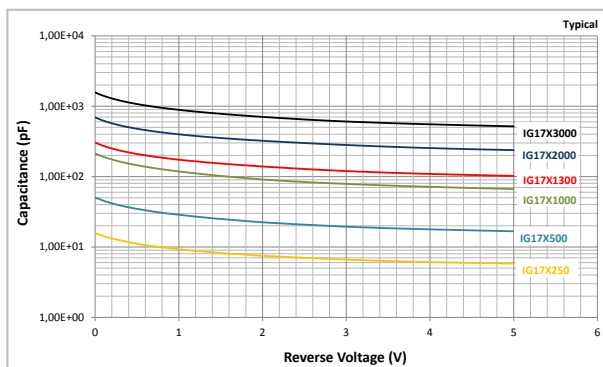


Fig. 6: Responsivity Temperature Coefficient I

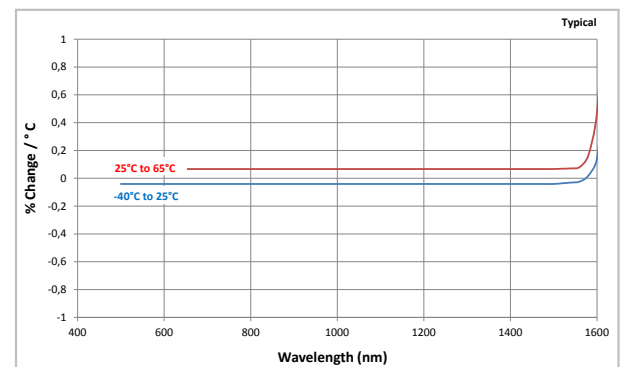


Fig. 7: Responsivity Temperature Coefficient II

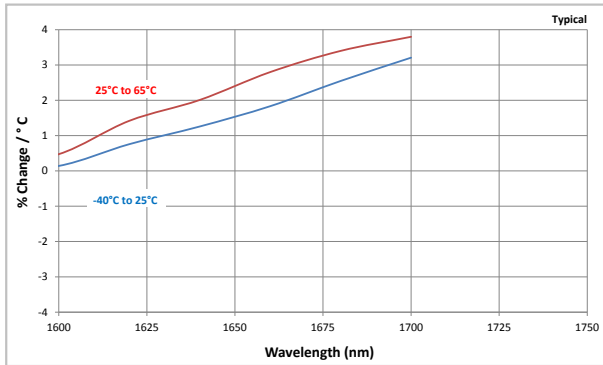


Fig. 8: Sample Pulse Response

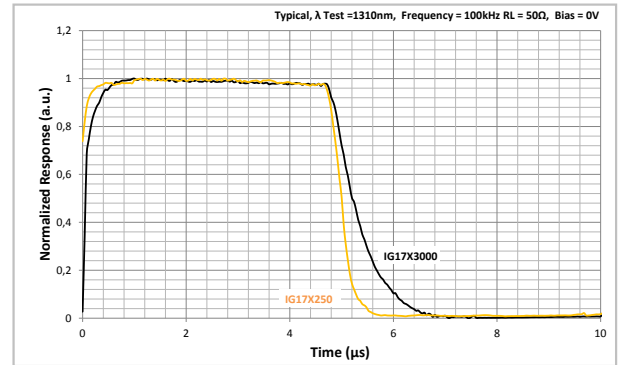
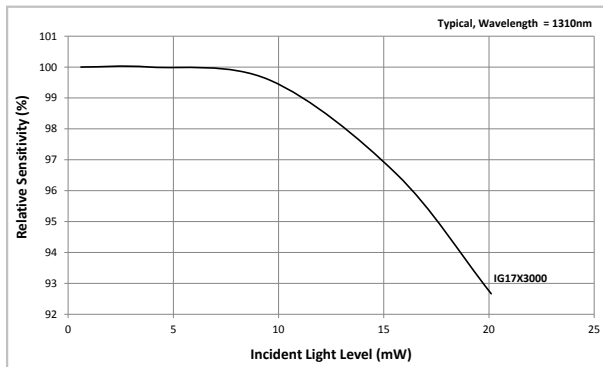


Fig. 9: Linearity



Nomenclature

C-	I	G	1	7	X		2	5	0	S	4	i	
Chip only	Type					Diameter				Package Style			
	Regular InGaAs PIN Photodiode					250 = 250 µm				S4i - TO-46, isolated			
						500 = 500 µm				S4ix - TO-46, no window			
						1000 = 1 mm				G1i - TO-39, isolated			
						1300 = 1.3 mm				G1ix - TO-39, no window			
						2000 = 2 mm				T7 - TO-37, single stage TEC			
						3000 = 3 mm				T9 - TO-66, dual stage TEC			
										M2 - 2 pad PCB SMD			
										L5 - TO-46 lens cap			

Note:

M2 package is high volume option for chip sizes up to 1 mm.
Please contact factory for availability.

Standard window: Borosilicate glass

Package drawings, TEC and thermistor curves can be found on a separate datasheet.

Product Changes

LASER COMPONENTS reserves the right to make changes to the product(s) or information contained herein without notice. No liability is assumed as a result of their use or application.

Ordering Information

Products can be ordered directly from LASER COMPONENTS or its representatives. For a complete listing of representatives, visit our website at www.lasercomponents.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Photodiodes](#) category:

Click to view products by [Laser Components](#) manufacturer:

Other Similar products are found below :

[LTR-526AD](#) [LV0221CS-TLM-H](#) [OED-SP-7L](#) [LTR-536AB](#) [LTR-743DBM1-TA](#) [LV0223CV-TLM-H](#) [67-21SYGC-S349-TR8](#) [SAH500M1](#)
[SFH 2200 A01](#) [BPW 34 S E9601](#) [SFH 2713](#) [SFH 2703](#) [LTR-546AD](#) [BP 104 SR-Z](#) [BPV23FL](#) [BPW 34 BS-Z](#) [BPW 34 FAS](#) [BPW 34 FS](#)
[IG17X1000S4I](#) [IG22X250S4I](#) [VTB9413BH](#) [VTD205H](#) [VTD205KH](#) [VTP1220FBH](#) [VTP1232FH](#) [VTP4085H](#) [1541201EEA400](#) [SFH 2400](#)
[OP913WSL](#) [OP955](#) [OPR5913](#) [PD15-21B/TR8](#) [PD3122FE000F](#) [PD93-21C/TR8](#) [LTR-536AD](#) [VTP8651H](#) [VTD206KH](#) [VTB1013H](#)
[BPV23NF](#) [OP905](#) [LTR-516AD](#) [BPW 34 FS-Z](#) [VTD34FH](#) [QSB34CGR](#) [SFH 2500 FA](#) [3001032](#) [3001048](#) [ARRAYC-60035-64P-PCB](#) [SFH](#)
[2240](#) [OPR2100T](#)